GENERAL PURPOSE TRANSISTORS

### NPA SILICON

## **DESCRIPTION**

The 2SC4081X is available in SC-70 Package.

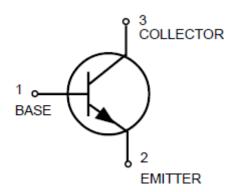
## **FEATURES**

- Low Cob, Cob=2pF(Typ.).
- Epitaxial planar type.
- PNP complement: 2SA1576A
- RoHS Compliant
- Available in SC-70 Package

# ORDERING INFORMATION

Package Type	Package Type Part Number		
	2SC4081Q		
SC-70	2SC4081R		
	2SC4081S		
Note 3,000PCS/Reel			
AiT provides all RoHS Compliant Products			

# PIN DESCRIPTION



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## **ABSOLUTE MAXIMUM RATINGS**

V <sub>CEO</sub> , Collector-Emitter Voltage	50V
V <sub>CBO</sub> , Collector-Base Voltage	60V
V <sub>EBO</sub> , Emitter-Base Voltage	7.0V
Ic, Collector Current	150mAdc
P <sub>C</sub> , Collector Power Dissipation	0.2W
T <sub>j</sub> , Junction Temperature	150°C
T <sub>stg</sub> , Storage Temperature	-55°C ~ +150°C

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

NOTE1: Pc must not be exceeded

#### her values are classified as follows:

*	Q	R	S
h <sub>EF</sub>	120~270	180~390	270~560

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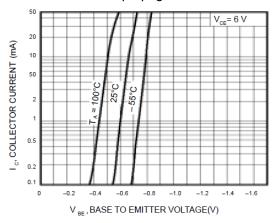
# **ELECTRICAL CHARACTERISTICS**

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	I <sub>C</sub> = 1mA	50	1	1	V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	I <sub>E</sub> = 50μA	7	1	1	V
Collector-base breakdown voltage	$V_{(BR)CBO}$	I <sub>C</sub> = 50μA	60	-	-	V
Collector cutoff current	Ісво	V <sub>CB</sub> = 60V	-	-	0.1	μΑ
Emitter cutoff current	I <sub>EBO</sub>	V <sub>EB</sub> = 7V	-	-	0.1	μΑ
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	Ic/Iв = 50mA /5mA	-	-	0.4	V
DC current transfer ratio	h <sub>EF</sub>	V <sub>CE</sub> = 6V ,I <sub>C</sub> = 1mA	120	-	560	-
Transition frequency	fτ	$V_{CE} = 12V, I_{E} = -2mA,$ $f = 30MHz$	-	180	-	MHz
Output capacitance	Cob	V <sub>CB</sub> =12V, I <sub>E</sub> =0A, f=1MHz	-	2.0	3.5	pF

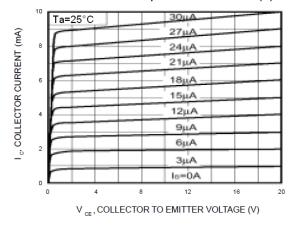
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TYPICAL PERFORMANCE CHARACTERISTICS

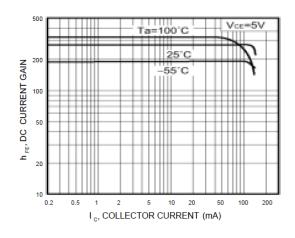
1. Grounded emitter propagation characteristics



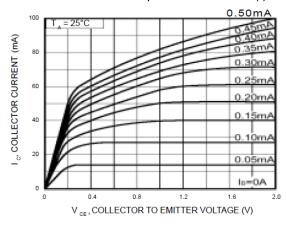
3. Grounded emitter output characteristics(II)



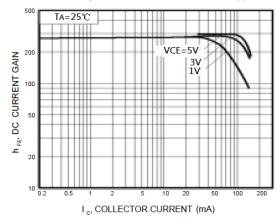
5. DC current gain vs. collector current (II)



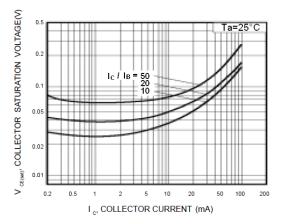
2. Grounded emitter output characteristics(I)



4. DC current gain vs. collector current (I)



6. Collector-emitter saturation voltage vs.

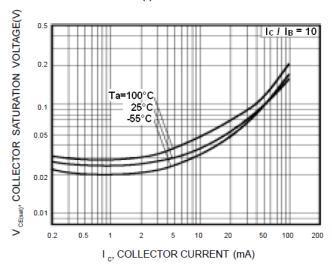


collector current

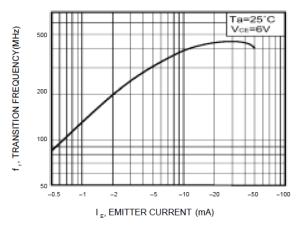
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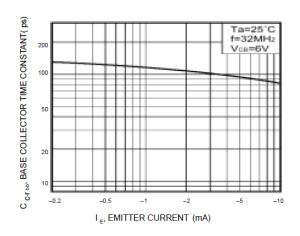
7. Collector-emitter saturation voltage vs. collector current (I)



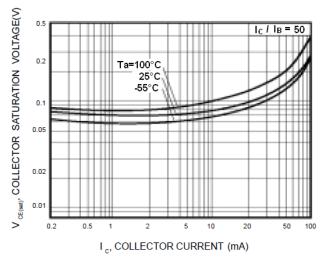
9. Gain bandwidth product vs. emitter current



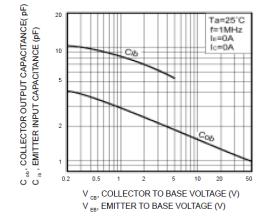
11. Base-collector time constant vs. emitter current



Collector-emitter saturation voltage vs. collector current (II)



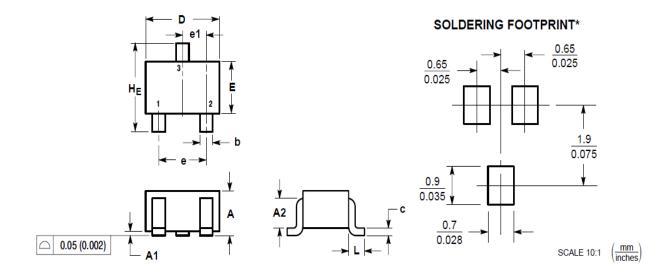
Collector output capacitance vs. collector-base voltage
 Emitter input capacitance vs. emitter-base voltage



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# **PACKAGE INFORMATION**

Dimension in SC-70 Package (Unit: mm)



DIM	MILLIMETERS		INCHES		
	MIN	MAX	MIN	MAX	
Α	0.80	1.00	0.032	0.040	
A1	0.00	0.10	0.000	0.004	
A2	0.7 REF		0.028 REF		
b	0.30	0.40	0.012	0.016	
С	0.10	0.25	0.004	0.010	
D	1.80	2.20	0.071	0.087	
Е	1.15	1.35	0.045	0.053	
е	1.20	1.40	0.047	0.055	
e1	0.65 BSC		0.02	6 BSC	
L	0.425 REF		0.017 REF		
HE	2.00	2.40	0.079	0.095	

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## **IMPORTANT NOTICE**

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